

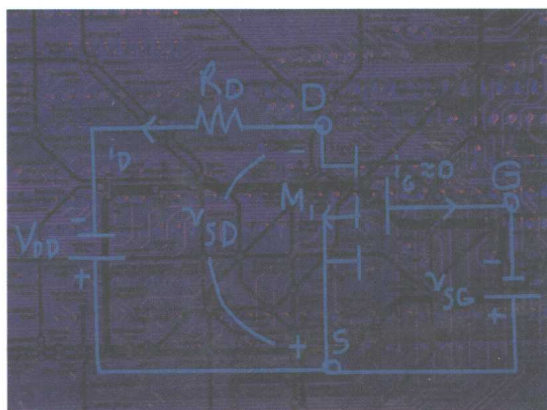
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国外高校电子信息类优秀教材

微电子电路分析与设计

Microelectronic Circuits: Analysis and Design

(英文影印版)



Muhammad H. Rashid 著



科学出版社

THOMSON
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内 容 简 介

本书为国外高校电子信息类优秀教材(英文影印版)之一。

本书介绍了微电子电路的设计过程、特点和分析方法,并介绍了二极管及其应用、放大设备和放大器、数字逻辑门、集成电路及其应用。

本书可作为电气工程和计算机专业的本科生教材,也可供相关专业技术人员参考。

Microelectronic Circuits: Analysis and Design

By Muhammad H. Rashid

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丛书编委会

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Preface

Semiconductor devices and integrated circuits are the backbone of modern technology, and thus the study of electronics—which deals with their characteristics and applications—is an integral part of the undergraduate curriculum for students majoring in electrical or computer engineering. Traditionally, the basic course in electronics has been a one-year (two-semester) course at most universities and colleges. However, with the emergence of new technologies and university-wide general education requirements, electrical engineering departments are under pressure to reduce basic electronics to a one-semester course. This book is designed to be used for either a one-semester or a two-semester course; the only prerequisite is a course in basic circuit analysis. A one-semester course would cover Chapters 1–11, in which the basic techniques for analyzing electronic circuits are introduced using integrated circuits as examples. In a two-semester course, the second semester would focus on detailed analysis of devices and circuits within the ICs.

The objectives of this book are as follows:

- To provide an understanding of the characteristics of semiconductor devices and commonly used integrated circuits
- To develop skills in analysis and design of both analog and digital circuits
- To familiarize students with various elements of the engineering design process, including formulation of specifications, analysis of alternative solutions, synthesis, decision making, iterations, consideration of cost factors, simulation, and tolerance issues.

This book adopts a top-down approach to the study of electronics, rather than the traditional bottom-up approach. In the classical bottom-up approach, the characteristics of semiconductor devices and ICs are studied first, and then the applications of ICs are introduced; such an approach generally requires a year of instruction, as it is necessary to cover all the essential materials in order to give students an overall knowledge of electronic circuits and systems. In the top-down approach used here, the ideal characteristics of IC packages are introduced to establish the design and analytical techniques, and then the characteristics and operation of devices and circuits within the ICs are studied to understand the imperfections and limitations of IC packages. This approach has the advantage of allowing the instructor to cover only the basic techniques and circuits in the first

semester, without going into detail on discrete devices. If the curriculum allows, the course can continue in the second semester with detailed analysis of discrete devices.

After an introduction to the design process in Chapter 1, the book may be divided into five parts:

- Chapters 2–3 on diodes and applications
- Chapters 4–7 on amplifying devices and amplifiers
- Chapters 8–11 on characteristics and analyses of electronic circuits
- Chapter 12 on digital logic gates
- Chapters 13–16 on integrated circuits and applications

A review of basic circuit analysis and an introduction to PSpice are included in the appendixes.

Modern semiconductor technology has evolved to such an extent that many analog and digital circuits are available in the form of integrated circuit packages. Manufacturers of these packages provide application notes, which can be used to implement circuit functions. Knowledge of the characteristics and operation of devices within the IC packages is essential, however, to understand the limitations of these ICs when they are interfaced as building blocks in circuit designs. Such knowledge also serves as the basis for developing future generations of IC packages.

Although the trend in IC technology suggests that discrete circuit design may disappear entirely in the future, transistor amplifiers (in large-scale or very-large-scale integrated forms) will continue to be the building blocks of ICs. Thus, transistor amplifiers are covered in Chapter 5, after the general types and specifications of amplifiers have been introduced in Chapter 4. Because diodes are the building blocks of many electronic circuits—and because the techniques for the analysis of diodes are similar to those for transistor amplifiers—diodes and their applications are addressed in detail in Chapters 2 and 3.

Mathematical derivations are kept to a minimum by using approximate circuit models of operational amplifiers, transistors, and diodes. The significance of these approximations is established by computer-aided analysis using PSpice. Important circuits are analyzed in worked-out examples in order to introduce the basic techniques and emphasize the effects of parameter variations. At the end of each chapter, review questions and problems test students' learning of the concepts developed in the chapter. Answers to selected problems appear in the back of the book.

In practice, the lectures and laboratory experiments run concurrently. If students' experimental results differ from the ideal characteristics because of the practical limitations of IC packages, students may become concerned. This concern may be addressed by a brief explanation of the causes of discrepancies. The experimental results, however, will not differ significantly from the theoretically obtained results.

Current ABET (Accreditation Board of Engineering and Technology) criteria require the integration of design and computer usage throughout the curriculum. After students have satisfied other ABET requirements in math, basic science, engineering science, general education electives, and free electives, they find that not many courses are available to satisfy the design requirements. The lack of opportunities for design credits in engineering curricula is a common concern. Electronics is generally the first electrical engineering course well suited to the integration of design components and computer usage. This book is structured to permit design content to constitute at least 50% of the course, and it integrates computer usage through PSpice. Many design examples use PSpice to verify the design requirements, and the numerous computer-aided design examples illustrate the usefulness of personal computers as design tools, especially in cases in which design variables are subjected to component tolerances and variations.

The CD-ROM bound into the back of this book contains tools that are designed to help the student learn about electronics more effectively. The CD includes

- the evaluation version of MicroSim PSpice® for Windows®-based computers and electronic copies of all the SPICE netlists printed in this book
- the evaluation version of the Student Edition of Electronics Workbench® for Windows®-based computers, which will load a set of files keyed to the book and allow students to work their own problems

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Dr. Nadeem N. Bunni
Clarkson University

Dr. Wai-Kai Chen
University of Illinois at Chicago

Dr. Shirshak K. Dhali
Southern Illinois University

Dr. Muhammed Farooq
*West Virginia University
Institute of Technology*

Dr. Constantine Hatziaioniu
Southern Illinois University

Dr. Bruce P. Johnson
University of Nevada-Reno

Dr. Frank Kornbaum
South Dakota State University

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Dr. Bahram Nabet
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Any comments and suggestions regarding this book are welcome. They should be sent to

Dr. Muhammad H. Rashid
Professor and Director
UF/UWF Joint Program in Electrical Engineering
University of West Florida
11000 University Parkway
Pensacola, FL 32514-5754
USA
e-mail: mrashid@uwf.edu
Web: <http://www.ee.uwf.edu>

Contents

Preface xvii

CHAPTER 1	1.1	Introduction	1
<i>Introduction to Electronics and Design</i>	1.2	History of Electronics	1
	1.3	Electronic Systems	3
		Sensors	3
		Actuators	3
	1.4	Electronic Signals and Notation	4
		Analog-to-Digital Converters	5
		Digital-to-Analog Converters	6
		Notation	6
	1.5	Classifications of Electronic Systems	7
	1.6	Specifications of Electronic Systems	9
		Transient Specifications	9
		Distortion	10
		Frequency Specifications	10
		dc and Small-Signal Specifications	11
	1.7	Design of Electronic Systems	12
	1.8	Design of Electronic Circuits	14
		Analysis versus Design	14
		Definition of Engineering Design	15
		The Circuit-Level Design Process	16
		Benefits of Studying from a Design Perspective	19
		Types of Design Projects	20
		Design Report	21
	1.9	Electronic Devices	21
		Semiconductor Diodes	21
		Bipolar Junction Transistors	22
		Field-Effect Transistors	22 •
		REFERENCES	26
		PROBLEMS	26
CHAPTER 2	2.1	Introduction	27
<i>Diodes</i>	2.2	Ideal Diodes	28
	2.3	Transfer Characteristic of Diode Circuits	31

2.4	Practical Diodes	32	
2.5	Physical Operation of Junction Diodes	32	
	Diode Junction	32	
	Forward-Biased Condition	34	
	Reverse-Biased Condition	34	
	Breakdown Condition	34	
2.6	Characteristic of Practical Diodes	35	
2.7	Determination of Diode Constants	37	
2.8	Temperature Effects	39	
2.9	Analysis of Practical Diode Circuits	41	
	Graphical Method	42	
	Approximate Method	42	
	Iterative Method	42	
2.10	Modeling of Practical Diodes	44	
	Constant-Drop dc Model	44	
	Piecewise Linear dc Model	44	
	Low-Frequency ac Model	46	
	High-Frequency ac Model	51	
	PSpice/SPICE Diode Model	53	
2.11	Zener Diodes	56	
	Zener Regulator	57	
	Design of a Zener Regulator	59	
	Zener Limiters	62	
	Temperature Effects on Zener Diodes	65	
2.12	Light-Emitting Diodes	66	
2.13	Schottky Barrier Diodes	66	
2.14	Power Rating	67	
2.15	Diode Data Sheets	69	
	SUMMARY	73	REFERENCES 73
	REVIEW QUESTIONS	73	PROBLEMS 74

CHAPTER 3

Applications of Diodes

3.1	Introduction	81	
3.2	Diode Rectifiers	81	
	Single-Phase Half-Wave Rectifiers	82	
	Single-Phase Full-Wave Center-Tapped Rectifiers	89	
	Single-Phase Full-Wave Bridge Rectifiers	94	
3.3	Output Filters for Rectifiers	99	
	L-Filters	99	
	C-Filters	102	
	LC-Filters	106	
3.4	Clippers	109	
	Parallel Clippers	109	
	Series Clippers	110	
3.5	Clamping Circuits	112	
	Fixed-Shift Clampers	112	
	Variable-Shift Clampers	113	
3.6	Peak Detectors and Demodulators	116	
3.7	Voltage Multipliers	120	
	Voltage Doublers	120	
	Voltage Triplers and Quadruplers	121	
3.8	Function Generators	123	
	SUMMARY	126	REFERENCES 126
	REVIEW QUESTIONS	126	PROBLEMS 127

CHAPTER 4

Introduction to Amplifiers

4.1	Introduction	133
4.2	Amplifier Characteristics	134
	Voltage Gain	134
	Current Gain	135
	Power Gain	135
	Logarithmic Gain	135
	Input and Output Resistances	136
	Amplifier Saturation	136
	Amplifier Nonlinearity	138
4.3	Amplifier Types	140
	Voltage Amplifiers	140
	Current Amplifiers	144
	Transconductance Amplifiers	148
	Transimpedance Amplifiers	150
4.4	PSpice/SPICE Amplifier Models	151
	Voltage Amplifier	152
	Current Amplifier	152
	Transconductance Amplifier	152
	Transimpedance Amplifier	152
4.5	Gain Relationships	152
	Voltage and Current Amplifiers	152
	Voltage and Transconductance Amplifiers	153
	Voltage and Transimpedance Amplifiers	153
4.6	Cascaded Amplifiers	154
	Cascaded Voltage Amplifiers	154
	Cascaded Current Amplifiers	155
4.7	Introduction to Transistor Amplifiers	156
	Bipolar Junction Transistors	156
	Field-Effect Transistors	161
4.8	Frequency Response of Amplifiers	165
	Low-Pass Characteristic	166
	High-Pass Characteristic	168
	Band-Pass Characteristic	170
	Gain and Bandwidth Relation	171
4.9	Miller's Theorem	172
4.10	Amplifier Design	175
	SUMMARY	178
	PROBLEMS	179
	REVIEW QUESTIONS	178

CHAPTER 5

Amplifying Devices

5.1	Introduction	185
5.2	Bipolar Junction Transistors	186
	Input and Output Characteristics	186
	BJT Models	188
	dc Biasing of BJTs	192
	Biasing Circuit Design	193
	Common-Emitter Amplifiers	196
	Emitter Followers	201
	Common-Base Amplifiers	205
	Amplifiers with Active Loads	209
5.3	Field-Effect Transistors	214
	Enhancement MOSFETs	215
	Depletion MOSFETs	218
	Junction Field-Effect Transistors	221

FET Models	223	
Biasing of FETs	227	
Common-Source Amplifiers	233	
Common-Drain Amplifiers	237	
Common-Gate Amplifiers	240	
FET Amplifiers with Active Loads	242	
5.4 FETs versus BJTs	245	
5.5 Design of Amplifiers	245	
BJT Amplifier Design	246	
FET Amplifier Design	249	
SUMMARY	252	REFERENCES 252
REVIEW QUESTIONS	252	PROBLEMS 253

CHAPTER 6

*Introduction to
Operational Amplifiers*

6.1	Introduction	267	
6.2	Characteristics of Ideal Op-Amps	268	
6.3	Op-Amp PSpice/SPICE Models	270	
	dc Linear Model	271	
	ac Linear Model	272	
	Nonlinear Macromodel	273	
6.4	Analysis of Ideal Op-Amp Circuits	273	
	Noninverting Amplifiers	274	
	Inverting Amplifiers	277	
	Differential Amplifiers	279	
6.5	Op-Amp Applications	281	
	Integrators	281	
	Differentiators	286	
	Instrumentation Amplifiers	289	
	Noninverting Summing Amplifiers	291	
	Inverting Summing Amplifiers	292	
	Addition-Subtraction Amplifiers	293	
	Optocoupler Drivers	296	
	Photodetectors	296	
	Voltage-Current Converters	297	
	dc Voltmeters	298	
	dc Millivoltmeters	298	
	Negative Impedance Converters	299	
	Constant Current Sources	300	
	Noninverting Integrators	301	
	Inductance Simulators	302	
	ac-Coupled Bootstrapped Voltage Followers	303	
6.6	Circuits with Op-Amps and Diodes	304	
	Most Positive Signal Detectors	305	
	Precision Peak Voltage Detectors	305	
	Precision Half-Wave Rectifiers	306	
	Precision Full-Wave Rectifiers	307	
	Precision Clamping Circuits	308	
	Fixed Voltage Limiters	309	
	Adjustable Voltage Limiters	310	
	Zener Voltage Limiters	315	
	Hard Limiters	316	
6.7	Op-Amp Circuit Design	319	
	SUMMARY	321	REFERENCES 321
	REVIEW QUESTIONS	321	PROBLEMS 322

CHAPTER 7
*Characteristics of
Practical Op-Amps*

7.1	Introduction	329
7.2	Internal Structure of Op-Amps	329
7.3	Parameters of Practical Op-Amps	330
	Input Resistance	331
	Output Resistance	331
	Input Capacitance	331
	Common-Mode Rejection Ratio	331
	Large-Signal Voltage Gain	333
	Rise Time	333
	Open-Loop Voltage Gain and Bandwidth	334
	Slew Rate	338
	Input Voltage Limits	339
	Output Voltage Limits	339
	Input Offset Voltage	339
	Input Biasing Current	341
	Input Offset Current	343
	Power Supply Rejection Ratio	345
	Thermal Drift	345
7.4	Offset Voltage Adjustment	347
7.5	Measurement of Offset Parameters	349
	SUMMARY	350
	REVIEW QUESTIONS	350
	REFERENCES	350
	PROBLEMS	350

CHAPTER 8
*Frequency Response
of Amplifiers*

8.1	Introduction	353
8.2	Frequency Model and Response of BJTs	354
	High-Frequency Model	354
	Small-Signal PSpice/SPICE Model	356
	Frequency Response of BJTs	356
8.3	Frequency Model and Response of FETs	360
	Frequency Model and Response of JFETs	360
	Frequency Model and Response of MOSFETs	361
	Small-Signal PSpice/SPICE Model	363
8.4	Bode Plots	364
	Low-Pass Amplifiers	365
	High-Pass Amplifiers	366
	Band-Pass Amplifiers	367
8.5	Amplifier Frequency Response	368
	Low Cutoff Frequencies	369
	High Cutoff Frequencies	370
8.6	Short-Circuit and Zero-Value Methods for Determining Break Frequencies	374
	Short-Circuit Method	374
	Zero-Value Method	376
	Mid-Band Voltage Gain	378
8.7	Frequency Response of Common-Emitter BJT Amplifiers	378
	Low Cutoff Frequencies	378
	High Cutoff Frequencies	380
8.8	Frequency Response of Common-Collector BJT Amplifiers	384
	Low Cutoff Frequencies	385
	High Cutoff Frequencies	386
8.9	Frequency Response of Common-Base BJT Amplifiers	388
	Low Cutoff Frequencies	388
	High Cutoff Frequencies	390

8.10	Frequency Response of FET Amplifiers	391
	Common-Source Amplifiers	392
	Common-Drain Amplifiers	395
	Common-Gate Amplifiers	397
8.11	Multistage Amplifiers	399
8.12	Frequency Response of Op-Amp Circuits	406
	Frequency Response of Op-Amp Integrators	406
	Frequency Response of Op-Amp Differentiators	408
8.13	Designing for Frequency Response	410
	SUMMARY	410
	REVIEW QUESTIONS	411
	REFERENCES	411
	PROBLEMS	411

CHAPTER 9*Active Filters*

9.1	Introduction	421
9.2	Active versus Passive Filters	421
9.3	Types of Active Filters	422
9.4	The Biquadratic Function	424
9.5	Butterworth Filters	425
	Butterworth Function for $n = 2$	426
	Butterworth Function for $n = 3$	426
9.6	Low-Pass Filters	427
	First-Order Low-Pass Filters	427
	Second-Order Low-Pass Filters	429
	Butterworth Low-Pass Filters	433
9.7	High-Pass Filters	436
	First-Order High-Pass Filters	436
	Second-Order High-Pass Filters	437
	Butterworth High-Pass Filters	440
9.8	Band-Pass Filters	442
	Wide Band-Pass Filters	443
	Narrow Band-Pass Filters	445
9.9	Band-Reject Filters	448
	Wide-Band-Reject Filters	448
	Narrow-Band-Reject Filters	451
9.10	All-Pass Filters	453
9.11	Switched Capacitor Filters	454
	Switched Capacitor Resistors	454
	Switched Capacitor Integrators	456
	Universal Switched Capacitor Filters	456
9.12	Filter Design Guidelines	458
	SUMMARY	459
	REVIEW QUESTIONS	459
	REFERENCES	459
	PROBLEMS	460

CHAPTER 10*Feedback Amplifiers*

10.1	Introduction	463
10.2	Feedback	464
10.3	Feedback Analysis	465
	Gain Sensitivity	467
	Feedback Factor Sensitivity	467
	Frequency Response	468
	Distortion	470
10.4	Feedback Topologies	472
10.5	Analysis of Feedback Amplifiers	474

10.6	Series-Shunt Feedback	476	
	Analysis of an Ideal Series-Shunt Feedback Network	477	
	Analysis of a Practical Series-Shunt Feedback Network	479	
10.7	Series-Series Feedback	485	
	Analysis of an Ideal Series-Series Feedback Network	486	
	Analysis of a Practical Series-Series Feedback Network	487	
10.8	Shunt-Shunt Feedback	493	
	Analysis of an Ideal Shunt-Shunt Feedback Network	494	
	Analysis of a Practical Shunt-Shunt Feedback Network	496	
10.9	Shunt-Series Feedback	502	
	Analysis of an Ideal Shunt-Series Feedback Network	503	
	Analysis of a Practical Shunt-Series Feedback Network	503	
10.10	Feedback Circuit Design	506	
10.11	Stability Analysis	511	
	Poles and Instability	512	
	Nyquist Stability Criterion	514	
	Relative Stability	516	
	Effects of Phase Margin	517	
	Stability Using Bode Plots	518	
10.12	Compensation Techniques	521	
	Addition of a Dominant Pole	521	
	Changing the Dominant Pole	523	
	Miller Compensation and Pole Splitting	524	
	Modification of the Feedback Path	526	
	SUMMARY	529	REFERENCES 530
	REVIEW QUESTIONS	530	PROBLEMS 531

CHAPTER 11

Oscillators

11.1	Introduction	541	
11.2	Principles of Oscillators	542	
	Frequency Stability	544	
	Amplitude Stability	545	
11.3	Phase-Shift Oscillators	545	
11.4	Quadrature Oscillators	549	
11.5	Three-Phase Oscillators	551	
11.6	Wien-Bridge Oscillators	552	
11.7	Colpitts Oscillators	556	
11.8	Hartley Oscillators	562	
11.9	Crystal Oscillators	564	
11.10	Active-Filter Tuned Oscillators	568	
11.11	Design of Oscillators	571	
	SUMMARY	572	REFERENCES 572
	REVIEW QUESTIONS	572	PROBLEMS 573

CHAPTER 12

Introduction to Digital Electronics

12.1	Introduction	577
12.2	Logic States	577
12.3	Logic Gates	578
12.4	Performance Parameters of Logic Gates	580
	Voltage Transfer Characteristic (VTC)	580
	Noise Margins	581
	Fan-Out and Fan-In	582
	Propagation Delay	584

	Power Dissipation	585
	Delay-Power Product	587
12.5	NMOS Inverters	588
	NMOS Inverter with Enhancement Load	588
	NMOS Inverter with Depletion Load	595
	Comparison of NMOS Inverters	601
12.6	NMOS Logic Circuits	602
	NMOS Transmission Gates	602
	NMOS NOR Gates	602
	NMOS NAND Gates	603
12.7	CMOS Inverters	603
12.8	CMOS Logic Circuits	608
	CMOS Transmission Gates	608
	CMOS NOR and NAND Gates	610
	CMOS Families	611
12.9	Comparison of CMOS and NMOS Gates	611
12.10	BJT Inverters	612
	Voltage Transfer Characteristic (VTC)	612
	Switching Characteristics	613
12.11	Transistor-Transistor Logic (TTL) Gates	617
	Standard TTL Gates	618
	High-Speed TTL NAND Gates	624
	Schottky TTL NAND Gates	628
12.12	Emitter-Coupled Logic (ECL) OR/NOR Gates	630
12.13	BiCMOS Inverters	636
	Propagation Delay	637
12.14	Interfacing of Logic Gates	638
	TTL Driving CMOS	639
	CMOS Driving TTL	641
12.15	Comparison of Logic Gates	641
12.16	Design of Logic Circuits	643
	SUMMARY	645
	REVIEW QUESTIONS	645
	REFERENCES	645
	PROBLEMS	646

CHAPTER 13

Active Sources and
Differential Amplifiers

13.1	Introduction	655
13.2	Internal Structure of Differential Amplifiers	656
13.3	BJT Current Sources	657
	Basic Current Source	657
	Modified Basic Current Source	659
	Widlar Current Source	661
	Cascode Current Source	664
	Wilson Current Source	665
	Multiple Current Sources	669
13.4	JFET Current Sources	670
13.5	MOSFET Current Sources	671
	Basic Current Source	671
	Multiple Current Sources	674
	Cascode Current Source	674
	Wilson Current Source	675
13.6	Design of Active Current Sources	676
13.7	Active Voltage Sources	676
	Impedance Transformation	677
	Negative Feedback	677
	Negative Feedback and Impedance Transformation	678

13.8	Characteristics of Differential Amplifiers	679
13.9	BJT Differential Amplifiers	681
	dc Transfer Characteristics	681
	Small-Signal Analysis	683
13.10	BJT Differential Amplifiers with Active Loads	689
	Small-Signal Analysis	690
	Differential Amplifier with Modified Current Mirror	692
	Cascode Differential Amplifier	693
13.11	JFET Differential Amplifiers	695
	JFET Differential Pair	695
	JFET Differential Pair with Active Load	702
13.12	MOS Differential Amplifiers	702
	NMOS Differential Pair	703
	MOS Differential Pair with Active Load	705
13.13	BiCMOS Differential Amplifiers	708
	BJT versus CMOS Amplifiers	708
	BiCMOS Amplifiers	709
	Cascode BiCMOS Amplifiers	710
13.14	Frequency Response of Differential Amplifiers	713
13.15	Design of Differential Amplifiers	715
	SUMMARY	715
	REVIEW QUESTIONS	715
	REFERENCES	715
	PROBLEMS	716

CHAPTER 14

Power Amplifiers

14.1	Introduction	723
14.2	Classification of Power Amplifiers	724
14.3	Emitter Followers	725
	Transfer Characteristic	726
	Signal Waveforms	726
	Output Power and Efficiency	726
14.4	Class A Amplifiers	729
	Basic Common-Emitter Amplifier	729
	Common-Emitter Amplifiers	732
	Transformer-Coupled Load Amplifier	733
14.5	Class B Push-Pull Amplifiers	735
	Complementary Push-Pull Amplifiers	735
	Transformer-Coupled Load Push-Pull Amplifier	740
14.6	Complementary Class AB Push-Pull Amplifiers	744
	Transfer Characteristic	744
	Output Power and Efficiency	745
	Biassing with Diodes	745
	Biassing with Diodes and an Active Current Source	746
	Biassing with a V_{BE} Multiplier	749
14.7	Quasi-Complementary Class AB Push-Pull Amplifiers	752
14.8	Transformer-Coupled Class AB Push-Pull Amplifiers	753
14.9	Short-Circuit and Thermal Protection	754
	Short-Circuit Protection	755
	Thermal Protection	755
14.10	Power Op-Amps	756
	IC Power Amplifiers	756
	Bridge Amplifier	759
14.11	Thermal Considerations	760
	Thermal Resistance	760
	Heat Sink and Heat Flow	760
	Power Dissipation versus Temperature	761

14.12 Design of Power Amplifiers 763

SUMMARY 763

REVIEW QUESTIONS 763

REFERENCES 763

PROBLEMS 764

CHAPTER 15
*Operational Amplifiers***15.1 Introduction 767****15.2 Internal Structure of Op-Amps 767****15.3 Op-Amp Parameters 768**

Input Biasing Current 769

Input Offset Current 769

Input Offset Voltage and Thermal Voltage Drift 769

Common Mode Rejection Ratio 771

Input Resistance 772

Output Resistance 775

Frequency Response 775

Slew Rate 778

15.4 JFET Op-Amps 779

JFET Op-Amp LH0022 780

JFET Op-Amp LF411 781

JFET Op-Amp LH0062 784

JFET Op-Amp LH0032 785

15.5 CMOS Op-Amps 787

CMOS Op-Amp MC14573 787

CMOS Op-Amp TLC1078 790

15.6 BiCMOS Op-Amps 792

BiCMOS Op-Amp CA3130 792

BiCMOS Op-Amp CA3140 793

15.7 BJT Op-Amps 795

BJT Op-Amp LM124 795

BJT Op-Amp LM741 796

15.8 Analysis of the LM741 Op-Amp 798

dc Analysis 798

Small-Signal ac Analysis 803

Analysis of Frequency Response 811

Small-Signal Equivalent Circuit 812

15.9 Design of Op-Amps 812

SUMMARY 813

REVIEW QUESTIONS 814

REFERENCES 813

PROBLEMS 814

CHAPTER 16
*Integrated Analog Circuits
and Applications***16.1 Introduction 817****16.2 Comparators 817**

Comparators versus Op-Amps 818

Output-Side Connection 818

Threshold Comparators 819

16.3 Zero-Crossing Detectors 821**16.4 Schmitt Triggers 822**

Inverting Schmitt Trigger 822

Noninverting Schmitt Trigger 825

Schmitt Trigger with Reference Voltage 826

Effects of Hysteresis on the Output Voltage 827

16.5 Square-Wave Generators 829**16.6 Triangular-Wave Generators 833**